	SN64BCT25244 25-Ω OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS SCBS477 – DECEMBER 1992 – REVISED JANUARY 1994
<ul> <li>State-of-the-Art BiCMOS Design</li></ul>	DW OR NT PACKAGE
Significantly Reduces I <sub>CCZ</sub>	(TOP VIEW)
<ul> <li>High-Impedance State During Power Up and</li></ul>	1Y1 1 24 1 <del>0E</del>
Power Down	GND 2 23 1A1
<ul> <li>ESD Protection Exceeds 2000 V Per</li></ul>	1Y2 3 22 1A2
MIL-STD-883C, Method 3015; Exceeds	1Y3 4 21 V <sub>CC</sub>
200 V Using Machine Model (C = 200 pF,	GND [ 5 20 ] 1A3
R = 0)	1Y4 [ 6 19 ] 1A4
<ul> <li>Designed to Facilitate Incident-Wave Switching for Line Impedances of 25 Ω or</li> </ul>	2Y1 07 18 2A1
Greater	2Y2 0 9 16 V <sub>CC</sub>
<ul> <li>Distributed V<sub>CC</sub> and GND Pins Minimize</li></ul>	2Y3 0 10 15 0 2A3
Noise Generated by the Simultaneous	GND 0 11 14 0 2 <u>A4</u>
Switching of Outputs	2Y4 12 13 2 <del>0E</del>

 Package Options Include Plastic Small-Outline (DW) Packages and Standard Plastic 300-mil DIPs (NT)

#### description

The SN64BCT25244 is a 25- $\Omega$  octal buffer and line driver designed specifically to improve both the performance and density of 3-state memory address drivers, clock drivers, and bus-oriented transceivers.

When the output-enable (1OE and 2OE) inputs are low, the device transmits data from the A inputs to the Y outputs. When  $1\overline{OE}$  and  $2\overline{OE}$  are high, the outputs are in the high-impedance state.

This buffer/driver is capable of sinking 188-mA  $I_{OL}$ , which facilitates switching 25- $\Omega$  transmission lines on the incident wave. The distributed V<sub>CC</sub> and GND pins minimize switching noise for more reliable system operation.

The outputs are in a high-impedance state during power up and power down while the supply voltage value is less than approximately 3 V.

The SN64BCT25244 is characterized for operation from -40°C to 85°C and 0°C to 70°C.

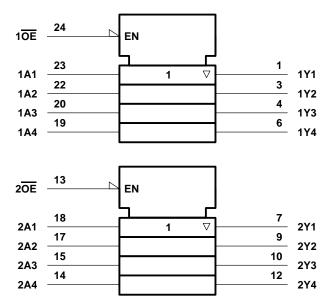
_	(each buffer/driver)								
	INP	JTS	OUTPUT						
ſ	OE	Α	Y						
ſ	L	Н	Н						
	L	L	L						
	Н	Х	Z						

#### **FUNCTION TABLE** (each huffer/driver)

## SN64BCT25244 25-Ω OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

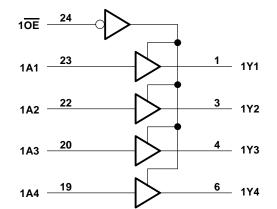
SCBS477 - DECEMBER 1992 - REVISED JANUARY 1994

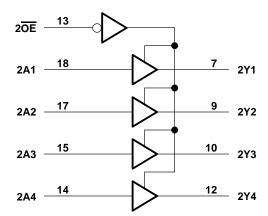
### logic symbol<sup>†</sup>



<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)





#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>‡</sup>

Supply voltage range, V <sub>CC</sub>	0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the disabled or power-off state, VO	0.5 V to 5.5 V
Voltage range applied to any output in the high state, VO	-0.5 V to V <sub>CC</sub>
Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)	–30 mA
Current into any output in the low state, I <sub>O</sub>	376 mA
Operating free-air temperature range	. −40°C to 85°C
Storage temperature range	–65°C to 150°C

<sup>‡</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.



### recommended operating conditions (see Note 2)

		MIN	NOM	MAX	UNIT
VCC	Supply voltage	4.5	5	5.5	V
VIH	High-level input voltage	2			V
VIL	Low-level input voltage			0.8	V
Iк	Input clamp current			-18	mA
ЮН	High-level output current			-80	mA
IOL	Low-level output current			188	mA
TA	Operating free-air temperature	-40		85	°C

NOTE 2: Unused or floating inputs must be held high or low.

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TES	MIN	түр†	MAX	UNIT	
VIK	V <sub>CC</sub> = 4.5 V,	lj = -18 mA			-1.2	V
Varia	V <sub>CC</sub> = 4.75 V,	I <sub>OH</sub> = – 3 mA	2.7			V
VOH	$V_{CC} = 4.5 V,$	I <sub>OH</sub> = -80 mA	2			v
Ve		I <sub>OL</sub> = 94 mA		0.42	0.55	V
VOL	$V_{CC} = 4.5 V$	I <sub>OL</sub> = 188 mA			0.7	v
10-	$V_{CC} = 0$ to 2.3 V (power up)	$V_{O} = 2.7 \text{ V or } 0.5 \text{ V}, \qquad \overline{\text{OE}} \text{ at } 0.8 \text{ V}$			±50	
IOZ	$V_{CC}$ = 2.3 to 0 (power down)	VO = 2.7 V of 0.5 V, OE at 0.8 V			±50	μA
lj	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 5.5 V			0.1	mA
ЧΗ	V <sub>CC</sub> = 5.5 V,	$V_{I} = 2.7 V$			20	μA
١ <sub>IL</sub>	V <sub>CC</sub> = 5.5 V,	V <sub>I</sub> = 0.5 V			-0.6	mA
IOZH	V <sub>CC</sub> = 5.5 V,	$V_{O} = 2.7 V$			50	μA
I <sub>OZL</sub>	V <sub>CC</sub> = 5.5 V,	$V_{O} = 0.5 V$			-50	μA
ICCL	V <sub>CC</sub> = 5.5 V,	Outputs open		90	119	mA
ІССН	V <sub>CC</sub> = 5.5 V,	Outputs open		59	78	mA
ICCZ	V <sub>CC</sub> = 5.5 V,	Outputs open		7	11	mA
Ci	V <sub>CC</sub> = 5 V,	VI = 2.5 V or 0.5 V		5.5		pF
Co	V <sub>CC</sub> = 5 V,	$V_{O} = 2.5 V \text{ or } 0.5 V$		17		pF

<sup>†</sup> All typical values are at  $V_{CC} = 5 \text{ V}$ ,  $T_A = 25^{\circ}\text{C}$ .

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Note 3)

PARAMETER	FROM TO (INPUT) (OUTPUT)	-	V <sub>CC</sub> = 5 V, T <sub>A</sub> = 25°C		T <sub>A</sub> = −40°C to 85°C		T <sub>A</sub> = 0°C to 70°C		UNIT	
		MIN	TYP	MAX	MIN	MAX	MIN	MAX		
<sup>t</sup> PLH	A	Y	1	3.2	4.9	1	5.6	1	5.5	ns
<sup>t</sup> PHL			2	4	5.6	2	6.3	2	6	
<sup>t</sup> PZH	ŌĒ	OE Y	3.2	5.6	8.5	3.2	9.7	3.2	9.3	ns
<sup>t</sup> PZL			3.7	6.3	9.2	3.7	10.4	3.7	10.2	
<sup>t</sup> PHZ	OE	tPHZ or	1.6	3.6	5.5	1.6	6.5	1.6	6.3	
<sup>t</sup> PLZ			3.1	5.3	7.8	3.1	9.5	3.1	8.4	ns

NOTE 3: Load circuits and voltage waveforms are shown in Section 1.



#### **IMPORTANT NOTICE**

Texas Instruments (TI) reserves the right to make changes to its products or to discontinue any semiconductor product or service without notice, and advises its customers to obtain the latest version of relevant information to verify, before placing orders, that the information being relied on is current.

TI warrants performance of its semiconductor products and related software to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

Certain applications using semiconductor products may involve potential risks of death, personal injury, or severe property or environmental damage ("Critical Applications").

TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, INTENDED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT APPLICATIONS, DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS.

Inclusion of TI products in such applications is understood to be fully at the risk of the customer. Use of TI products in such applications requires the written approval of an appropriate TI officer. Questions concerning potential risk applications should be directed to TI through a local SC sales office.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards should be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance, customer product design, software performance, or infringement of patents or services described herein. Nor does TI warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used.

Copyright © 1996, Texas Instruments Incorporated